



## UR6515C

## LINEAR INTEGRATED CIRCUIT

### 2A DDR BUS TERMINATION REGULATOR

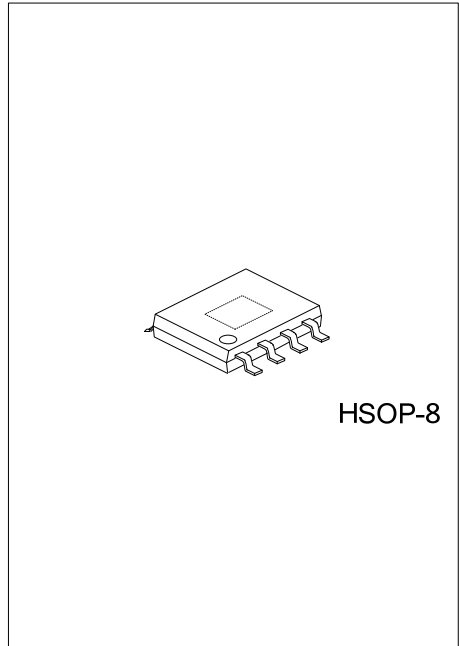
#### DESCRIPTION

The **UR6515C** is a linear regulator providing up to 2A transient peak current sourcing and sinking capability for DDR SDRAM bus terminator applications while regulating an output voltage to within 40mV. It contains a high speed operational amplifier which provides fast load transient response and only requires 10uF of ceramic output capacitance.

The **UR6515C** output termination voltage tracks the reference voltage applied at  $V_{REF}$  pin. A resistor divider connected to  $V_{IN}$ , GND and  $V_{REF}$  pins is used to force the reference voltage to  $V_{REF}$  pin. Additional features include current limiting protection and thermal shutdown protection.

#### FEATURES

- \*DDR1/ DDR2/DDR3 termination voltage applications
- \*Sink and Source Current  
2A Continuous Current
- \*Adjustable output voltage by external resistors
- \*Integrated power MOS devices
- \*Suspend to RAM(STR) functionality
- \*Current Limiting Protection
- \*Thermal Shutdown Protection
- \*Cost-effective and easy to use

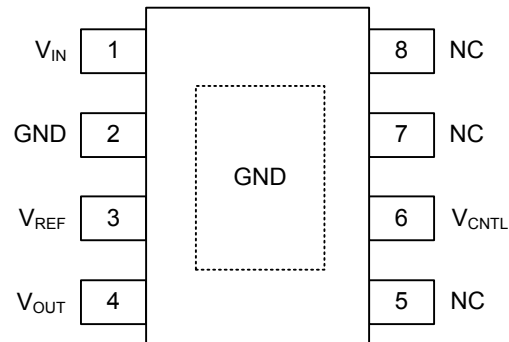


#### ORDERING INFORMATION

Ordering Number		Package	Packing
Lead Free	Halogen Free		
UR6515CL-SH2-R	UR6515CG-SH2-R	HSOP-8	Tape Reel
UR6515CL-SH2-T	UR6515CG-SH2-T	HSOP-8	Tube

<p>UR6515CL-SH2-R</p> <p>(1) Packing Type (2) Package Type (3) Lead Free</p>	<p>(1) R: Tape Reel, T: Tube (2) SH2: HSOP-8 (3) G: Halogen Free, L: Lead Free</p>
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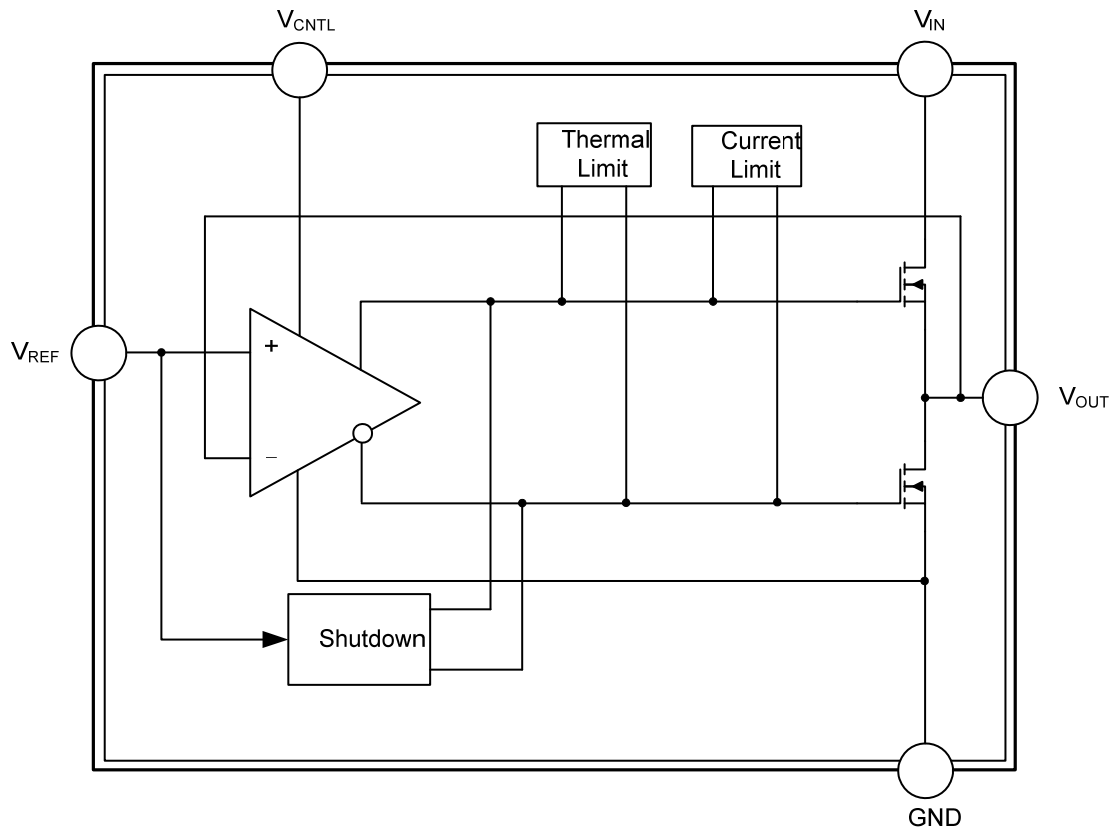
### ■ PIN CONFIGURATIONS



### ■ PIN DESCRIPTION

PIN NAME	PIN TYPE	PIN DESCRIPTION
V <sub>CTRL</sub>	I	Power supply pin for the internal control circuits
GND	-	Ground pin
V <sub>IN</sub>	I	Power supply pin for the V <sub>OUT</sub> output
V <sub>REF</sub>	I	Reference voltage input and active-low shutdown control pin
V <sub>OUT</sub>	O	Output voltage pin

### ■ BLOCK DIAGRAM



### ■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
V <sub>CNTL</sub> Control Voltage	V <sub>CNTL</sub>	+6	V
V <sub>IN</sub> Supply Voltage	V <sub>IN</sub>	+6	V
Power Dissipation (T <sub>A</sub> =25°C)	P <sub>D</sub>	1.33	W
Junction Temperature	T <sub>J</sub>	125	°C
Storage Temperature	T <sub>STG</sub>	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.  
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### ■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 1)	θ <sub>JA</sub>	75	°C/W
Junction to Case	θ <sub>JC</sub>	28	°C/W

Note: 1. θ<sub>JA</sub> is measured in the natural convection at T<sub>A</sub> = 25°C on a high effective thermal conductivity test board of JEDEC 51-7 thermal measurement standard

### ■ RECOMMENDED OPERATING CONDITIONS (Note 1)

PARAMETER	SYMBOL	RATINGS	UNIT
V <sub>CNTL</sub> Control Voltage	V <sub>CNTL</sub>	5 or 3.3±5%	V
V <sub>IN</sub> Supply Voltage	V <sub>IN</sub>	2.5~1.5±3%	V
V <sub>REF</sub> Input Voltage	V <sub>REF</sub>	1.25~0.75±3%	V
Junction Temperature	T <sub>J</sub>	-40~+125	°C

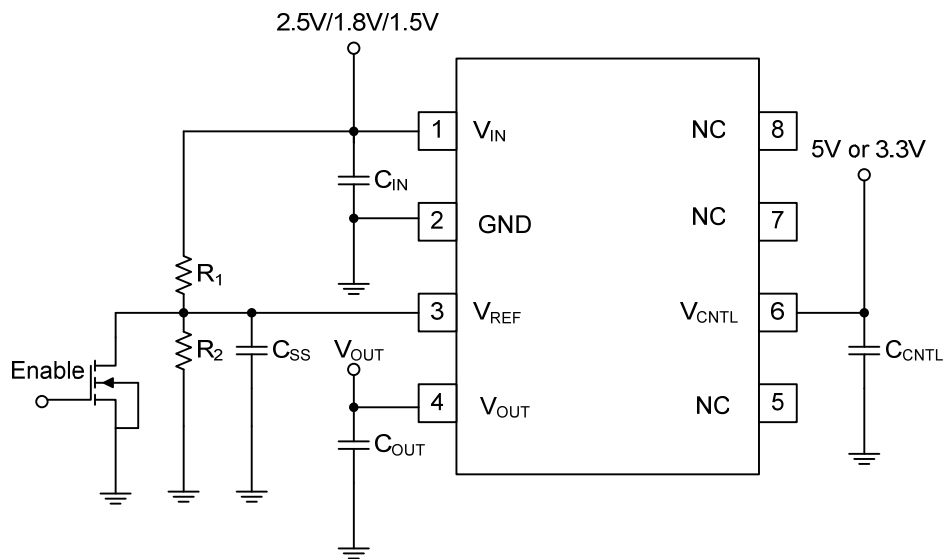
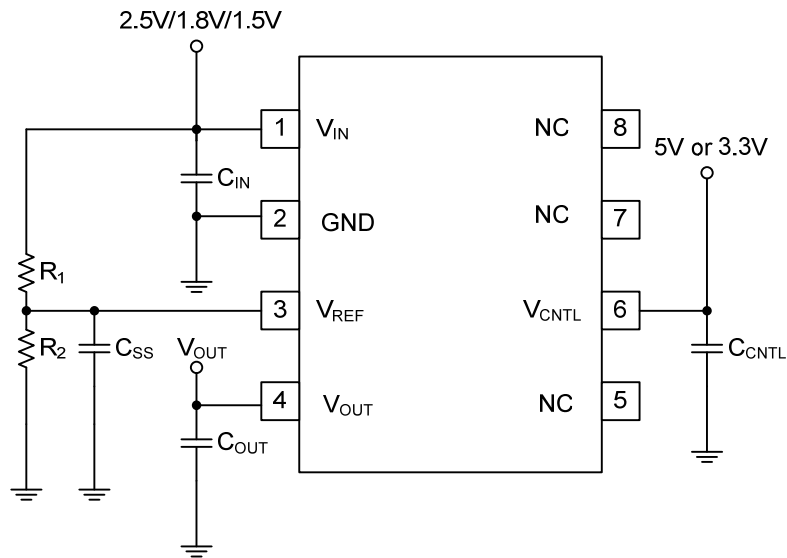
Notes: 1. All voltage values are with respect to the network ground terminal unless otherwise noted.  
2. The V<sub>OUT</sub> tracks the V<sub>REF</sub> with additional voltage offset and load regulation.

### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified)

(V<sub>IN</sub>=2.5V/1.8V/1.5V, V<sub>CNTL</sub>=3.3V, V<sub>REF</sub>=1.25V/0.9V/0.75V, C<sub>OUT</sub> = 10μF (Ceramic))

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>INPUT CURRENT</b>						
Operation Current of V <sub>CNTL</sub>	I <sub>CNTL</sub>	I <sub>OUT</sub> = 0A		1	2.5	mA
Standby Current	I <sub>STB</sub>	V <sub>REF</sub> < 0.2V, R <sub>LOAD</sub> = 180Ω		50	90	μA
<b>OUTPUT VOLTAGE (DDR/DDR II/DDR III)</b>						
Output Voltage Offset (V <sub>REF</sub> -V <sub>OUT</sub> )	V <sub>OS</sub>	I <sub>OUT</sub> = 0A	-20		20	mV
Load Regulation	ΔV <sub>LOAD</sub>	I <sub>OUT</sub> = ±2A	-20		20	mV
<b>PROTECTION</b>						
Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> = 2.5V/1.8V/1.5V	2.2			A
Thermal Shutdown Temperature	T <sub>SD</sub>	V <sub>CNTL</sub> = 3.3V~5V	125	170		°C
Thermal Shutdown Hysteresis	ΔT <sub>SD</sub>	V <sub>CNTL</sub> = 3.3V~5V		35		°C
<b>V<sub>REF</sub> Shutdown</b>						
Shutdown Threshold	V <sub>IH</sub>	Enable	0.6			V
	V <sub>IL</sub>	Shutdown			0.2	V

### ■ TYPICAL APPLICATIONS CIRCUITS

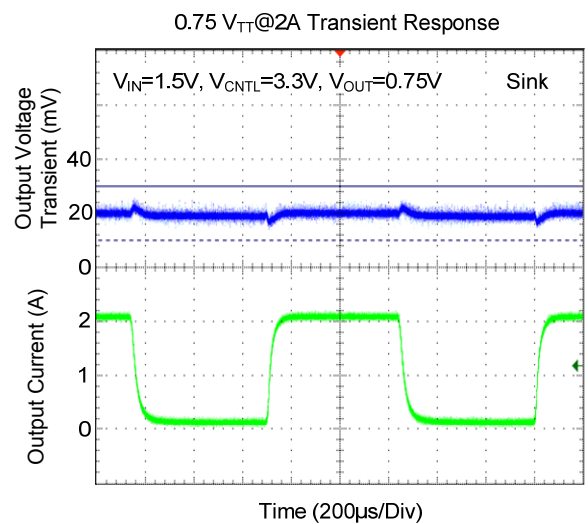
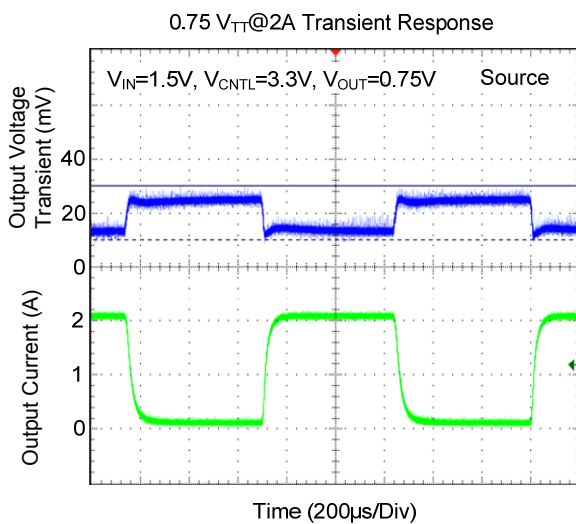
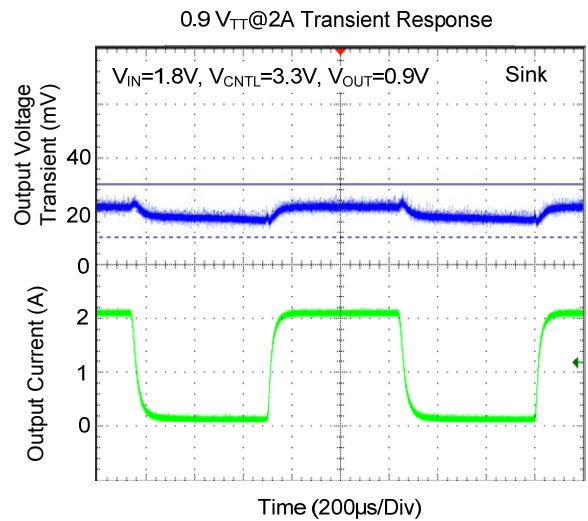
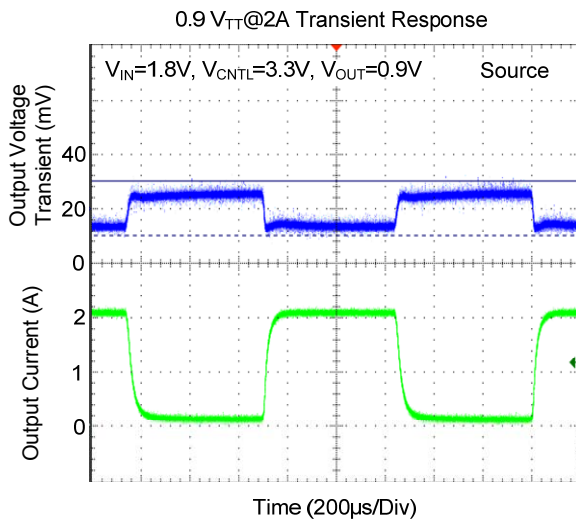
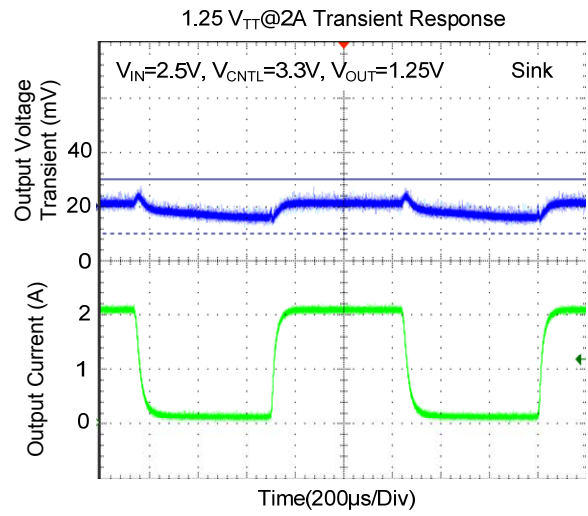
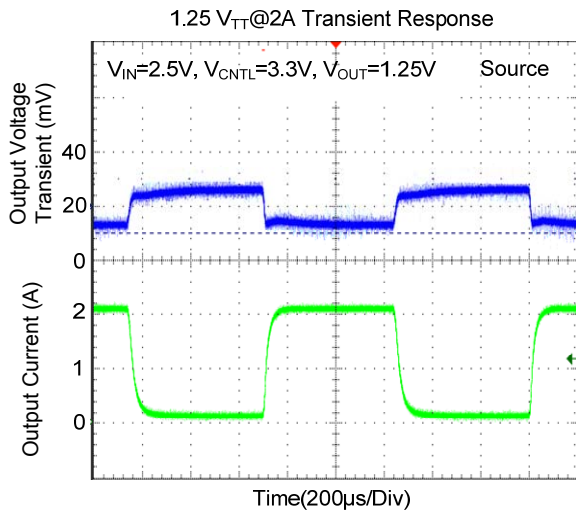


$R_1=R_2=100\text{K}\Omega$ ,  $C_{OUT}=10\mu\text{F}(\text{Ceramic})+1000\mu\text{F}$  under the worst case testing condition

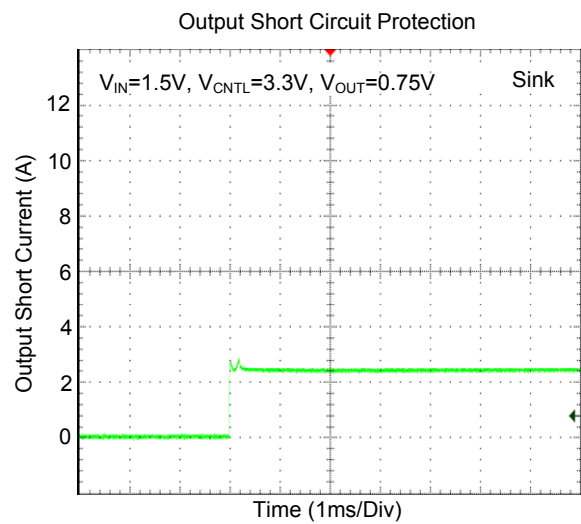
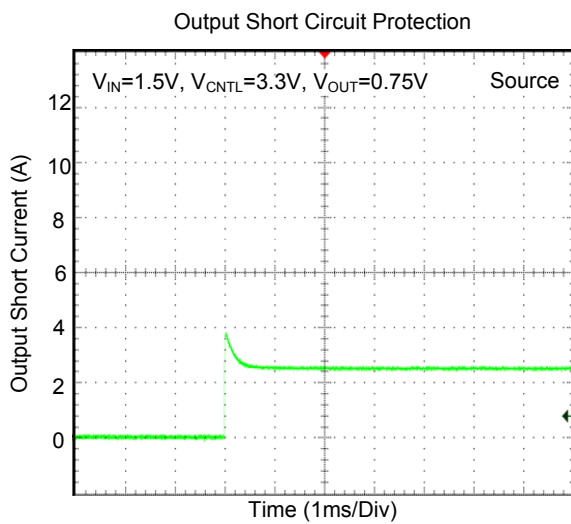
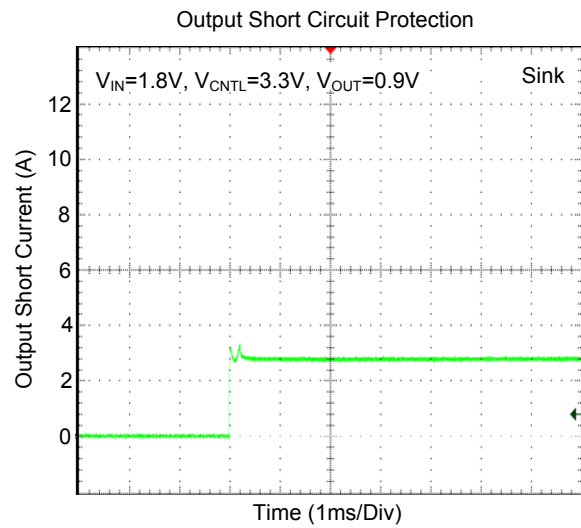
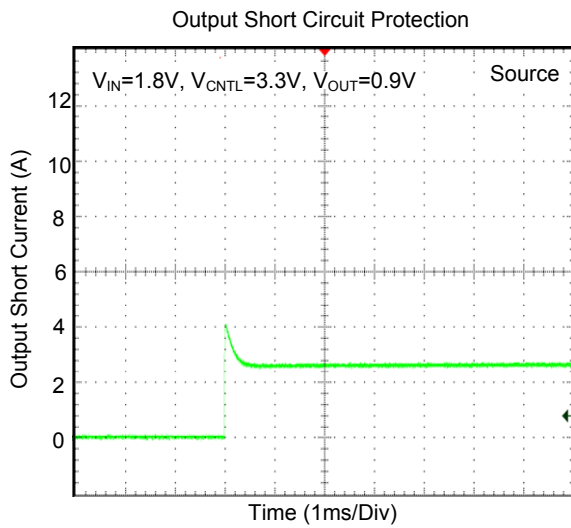
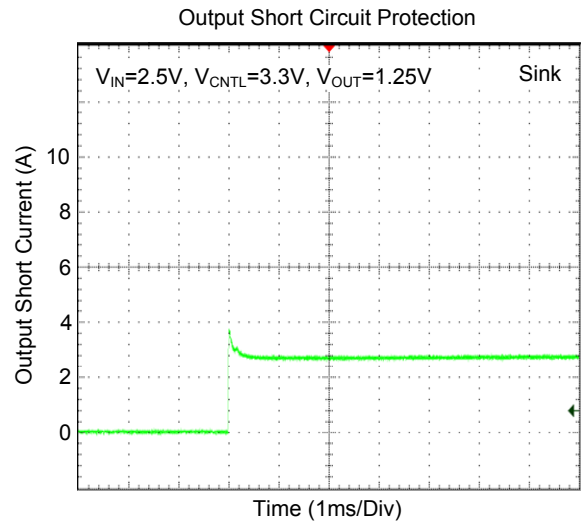
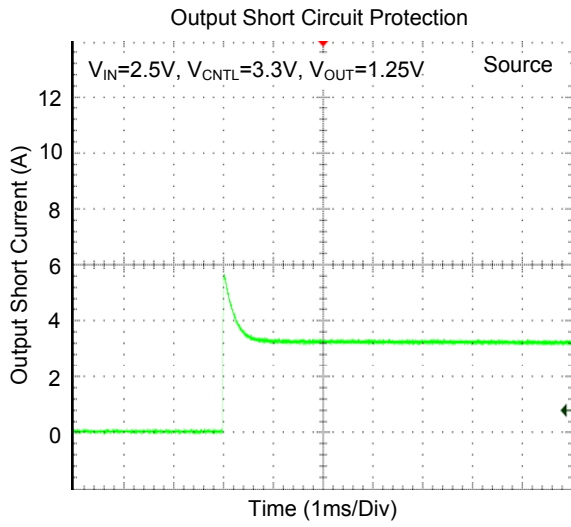
$C_{SS}=1\mu\text{F}$ ,  $C_{IN}=470\mu\text{F}(\text{Low ESR})$ ,  $C_{CNTRL}=47\mu\text{F}$

$$V_{REF} = \frac{R_2}{R_1 + R_2} V_{IN}(V), V_{OUT} \text{ track } V_{REF}$$

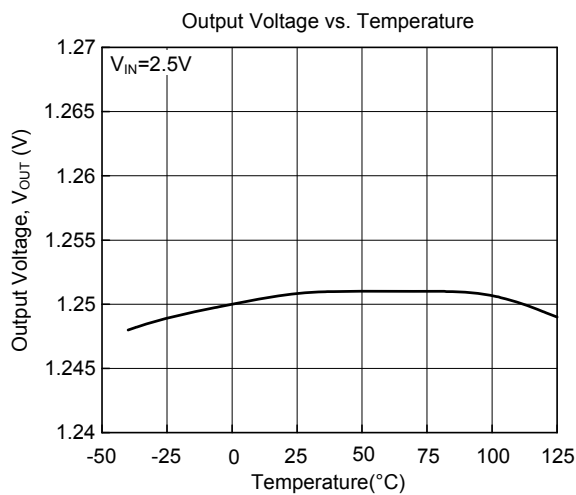
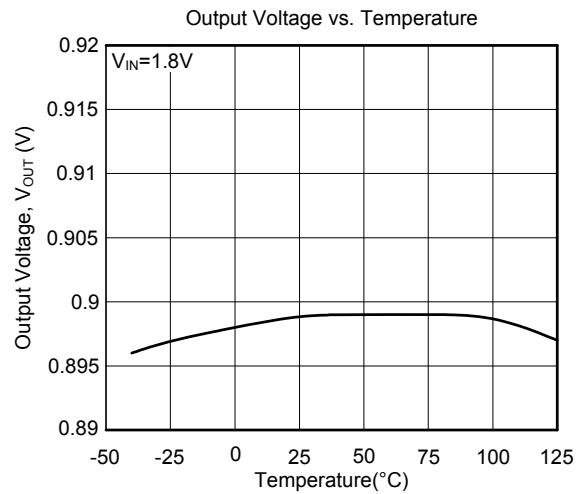
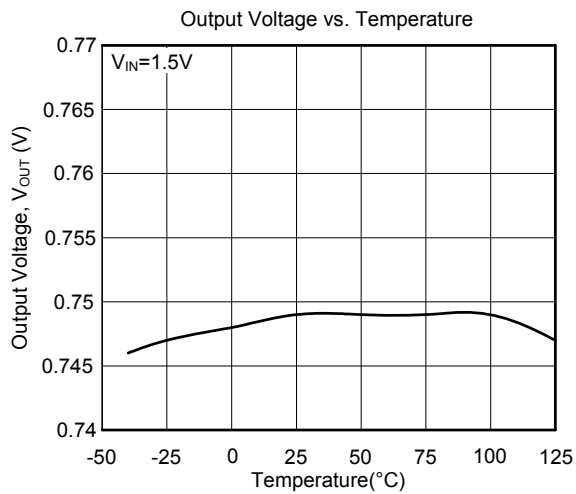
## TYPICAL CHARACTERISTICS



## ■ TYPICAL CHARACTERISTICS(Cont.)



### ■ TYPICAL CHARACTERISTICS(Cont.)



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